## HIGH CURRENT NPN SILICON TRANSISTOR

- SGS-THOMSON PREFERRED SALESTYPE
- NPN TRANSISTOR


## APPLICATIONS

- HORIZONTAL DEFLECTION FOR MONOCHROME TVs


## DESCRIPTION

The BU407 is a silicon epitaxial planar NPN transistors in Jedec TO-220 plastic package.
They are fast switching, high voltage devices foe use in horizontal deflection output stages of medium and small screens MTV receivers with $110^{\circ}$ CRT as monochrome computers terminals.


TO-220

## INTERNAL SCHEMATIC DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{V}_{\mathrm{CBO}}$ | Collector-Base Voltage $\left(\mathrm{I}_{\mathrm{E}}=0\right)$ | 330 | V |
| $\mathrm{~V}_{\mathrm{CEV}}$ | Collector-Emitter Voltage $\left(\mathrm{V}_{\mathrm{BE}}=-1.5 \mathrm{~V}\right)$ | 330 | V |
| $\mathrm{~V}_{\mathrm{CEO}}$ | Collector-Emitter Voltage $\left(\mathrm{I}_{\mathrm{B}}=0\right)$ | 150 | V |
| $\mathrm{~V}_{\mathrm{EBO}}$ | Emitter-Base Voltage $\left(\mathrm{IC}_{\mathrm{C}}=0\right)$ | 6 | V |
| $\mathrm{I}_{\mathrm{C}}$ | Collector Current | 7 | A |
| $\mathrm{I}_{\mathrm{CM}}$ | Collector Peak Current (repetitive) | 10 | A |
| $\mathrm{I}_{\mathrm{CM}}$ | Collector Peak Current $\left(\mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}\right)$ | 15 | A |
| $\mathrm{I}_{\mathrm{B}}$ | Base Current | 4 | A |
| $\mathrm{P}_{\text {tot }}$ | Total Dissipation at $\mathrm{T}_{\mathrm{C}} \leq 25^{\circ} \mathrm{C}$ | 60 | C |
| $\mathrm{T}_{\text {stg }}$ | Storage Temperature | -65 to 150 | 150 |
| $\mathrm{~T}_{\mathrm{j}}$ | Max. Operating Junction Temperature |  | ${ }^{\circ} \mathrm{C}$ |

## THERMAL DATA

| $\mathrm{R}_{\mathrm{thj} \text {-case }}$ | Thermal Resistance Junction-case | Max | 2.08 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{R}_{\mathrm{thj} \text {-amb }}$ | Thermal Resistance Junction-ambient | Max | 70 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\text {case }}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Symbol | Parameter | Test Conditions |  | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Ices | Collector Cut-off Current ( $\mathrm{V}_{\mathrm{BE}}=0$ ) | $\begin{aligned} & V_{C E}=330 \mathrm{~V} \\ & V_{C E}=200 \mathrm{~V} \\ & V_{C E}=200 \mathrm{~V} \end{aligned}$ | $T_{\text {case }}=100^{\circ} \mathrm{C}$ |  |  | $\begin{gathered} 5 \\ 100 \\ 1 \end{gathered}$ | $\begin{aligned} & \mathrm{mA} \\ & \mu \mathrm{~A} \\ & \mathrm{~mA} \end{aligned}$ |
| $I_{\text {ebo }}$ | Emitter Cut-off Current $(\mathrm{I} C=0)$ | $\mathrm{V}_{\mathrm{Eb}}=6 \mathrm{~V}$ |  |  |  | 1 | mA |
| $\mathrm{V}_{\text {CE(sat)* }}$ | Collector-emitter Saturation Voltage | $\mathrm{IC}_{\mathrm{C}}=5 \mathrm{~A}$ | $\mathrm{I}_{\mathrm{B}}=0.5 \mathrm{~A}$ |  |  | 1 | V |
| $\mathrm{V}_{\mathrm{BE} \text { (sat)* }}$ | Base-emitter Saturation Voltage | $\mathrm{IC}_{\mathrm{C}}=5 \mathrm{~A}$ |  |  |  | 1.2 | V |
| $\mathrm{f}_{T}$ | Transition-Frequency | $\begin{aligned} & \mathrm{I} \mathrm{C}=1 \mathrm{~A} \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | $\mathrm{V}_{\text {CE }}=5 \mathrm{~V}$ |  | 10 | 16 | MHz |
| $\mathrm{t}_{\text {off** }}$ | Turn-off Time | $\mathrm{IC}_{\mathrm{C}}=5 \mathrm{~A}$ | $\mathrm{I}_{\text {Bend }}=0.5 \mathrm{~A}$ |  |  | 0.75 | $\mu \mathrm{s}$ |
| $\mathrm{I}_{\mathrm{s} / \mathrm{b}}$ | Second Breakdown Collector Current | $\mathrm{V}_{\text {CE }}=40 \mathrm{~V}$ | $\mathrm{t}=10 \mathrm{~ms}$ |  | 4 |  | A |

* Pulsed: Pulse duration = $300 \mu \mathrm{~s}$, duty cycle $1.5 \%$.


## TO-220 MECHANICAL DATA

| DIM. | mm |  |  | inch |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 4.40 |  | 4.60 | 0.173 |  | 0.181 |
| C | 1.23 |  | 1.32 | 0.048 |  | 0.051 |
| D | 2.40 |  | 2.72 | 0.094 |  | 0.107 |
| D1 |  | 1.27 |  |  | 0.050 |  |
| E | 0.49 |  | 0.70 | 0.019 |  | 0.027 |
| F | 0.61 |  | 0.88 | 0.024 |  | 0.034 |
| F1 | 1.14 |  | 1.70 | 0.044 |  | 0.067 |
| F2 | 1.14 |  | 1.70 | 0.044 |  | 0.067 |
| G | 4.95 |  | 5.15 | 0.194 |  | 0.203 |
| G1 | 2.4 |  | 2.7 | 0.094 |  | 0.106 |
| H2 | 10.0 |  | 10.40 | 0.393 |  | 0.409 |
| L2 |  | 16.4 |  |  | 0.645 |  |
| L4 | 13.0 |  | 14.0 | 0.511 |  | 0.551 |
| L5 | 2.65 |  | 2.95 | 0.104 |  | 0.116 |
| L6 | 15.25 |  | 15.75 | 0.600 |  | 0.620 |
| L7 | 6.2 |  | 6.6 | 0.244 |  | 0.260 |
| L9 | 3.5 |  | 3.93 | 0.137 |  | 0.154 |
| DIA. | 3.75 |  | 3.85 | 0.147 |  | 0.151 |



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